



**SKiiP stack**

## SEMISTACK® Renewable Energy - Size W2

Two Quadrant 3-phase IGBT inverter

Ordering No. 08800415

Description SKS B2 120 GD 69/11 - MA PB

### Features

- Designed in regard to EN50178 and UL508C recommendations
- Designed for a 600 x 600 x 2000 mm cabinet
- Embedded SKiiP® Technology 3
- SKiiP 2403GB172-4DW, Trench 3 1700V IGBT, CAL3 diode
- Integrated current and temperature sensors
- Water cooling

### Typical Applications

- Wind generators (SG and DFIG)
- Solar Inverters

### Footnotes

<sup>1)</sup> Absolute maximum ratings are values not to be exceeded in any case and do not imply that the stack can operate in all these conditions taken together.

<sup>2)</sup> fan consumption and losses in air included

### REMARKS

This technical information specifies semiconductor devices but promises no characteristics. No warranty or guarantee, expressed or implied is made regarding delivery, performance or suitability.

### Absolute maximum ratings <sup>1)</sup>

Symbol	Conditions	Values	Unit
I <sub>OUT MAX</sub>	Maximum permanent output current	1 200	A <sub>RMS</sub>
I <sub>IN MAX</sub>	Maximum permanent input current	1 800	A <sub>DC</sub>
V <sub>OUT MAX</sub>	Maximum output voltage	760	V <sub>AC</sub>
V <sub>BUS MAX</sub>	Maximum DC Bus voltage	1 200	V <sub>DC</sub>
F <sub>OUT MAX</sub>	Inverter output frequency	100	Hz
F <sub>SW MAX</sub>	Maximum switching frequency	5	kHz

### Electrical characteristics: application example

T<sub>AMBIENT</sub>=40°C unless otherwise specified

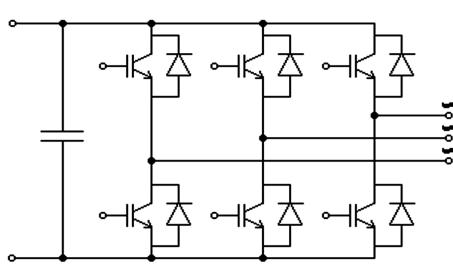
Symbol	Conditions	min	typ	max	Unit
<b>AC phase</b>					
V <sub>BUS</sub>	DC bus rated voltage		1 100		V <sub>DC</sub>
I <sub>OUT RATED</sub>	Rated output current		1 200		A <sub>RMS</sub>
I <sub>OUT OVL</sub>	Overload output current		1 320		A <sub>RMS</sub>
t <sub>OVL</sub>	Overload duration	60		s	
T <sub>OVL</sub>	Time between 2 overloads	10		min	
V <sub>OUT</sub>	Output voltage	620	690	760	V <sub>AC</sub>
P <sub>OUT</sub>	Rated output power		1 430		kW
F <sub>SW</sub>	Inverter switching frequency	2		kHz	
F <sub>OUT</sub>	Output frequency	50		Hz	
PF	Power factor	1		-	
P <sub>LOSS INV</sub> <sup>2)</sup>	Losses at rated current		13 840		W
η <sup>2)</sup>	Efficiency at rated current		>99		%

### DC Bus

V <sub>BUS</sub>	Rated DC voltage applied to the capacitor bank	1 100	V <sub>DC</sub>
V <sub>BUS MAX</sub>	Max DC voltage applied to the caps bank (max 30% of LTE)	1 200	V <sub>DC</sub>
τ <sub>ds%</sub>	Discharge time of the capacitors (V <sub>DC</sub> < 60 V)	7	min
C <sub>DC</sub>	Capacitor bank capacity	10,0	mF
LTE	Calculated LTE of the caps with forced air cooling	100	kh

### Stack Insulation

Crd	Minimum creepage distance	11	mm
Cld	Minimum clearance distance	9.4	mm
Visol	Chassis / power stage AC/DC (insulation test voltage DC, 5s)	-4 200	4 200
dv/dt	SKiiP driver only, secondary to primary side	75	kV/μs



**B6CI**

**SKS B2 120 GD 69/11 - MA PB**



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  - Integrated current and temperature sensors
  - Water cooling

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  - Solar Inverters

## Footnotes

<sup>3)</sup> the user shall ensure that the ambient air is sufficiently ventilated to avoid hot spots.

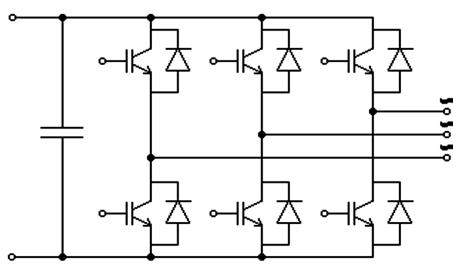
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Environmental conditions		T_AMBIENT=40°C unless otherwise specified			
Characteristics	Conditions	min	typ	max	Unit
<b>Climatic</b>					
Ambient temperature <sup>3)</sup>	Storage: IEC 60721-3-1, class 1K2	-25	60		°C
	Transportation: IEC 60721-3-2, class 2K2	-20	55		°C
Humidity	Operation: IEC 60721-3-3, class 3K3 extended no condensation no icing	5	85		%
<b>Mechanical</b>					
Installation altitude	without derating		1 000		m
Max installation altitude	with derating		4 000		m
Ingress protection	IEC 60529		IP00		-
Vibrations & Shocks	IEC 60721-3-2, Storage & transportation		2M1		-
	IEC 60721-3-3, in operation		3M3		-
Pollution degree	EN 50178		2		-
Weight	3-phase inverter, with cable plate terminal and no DC bus connection		98		kg

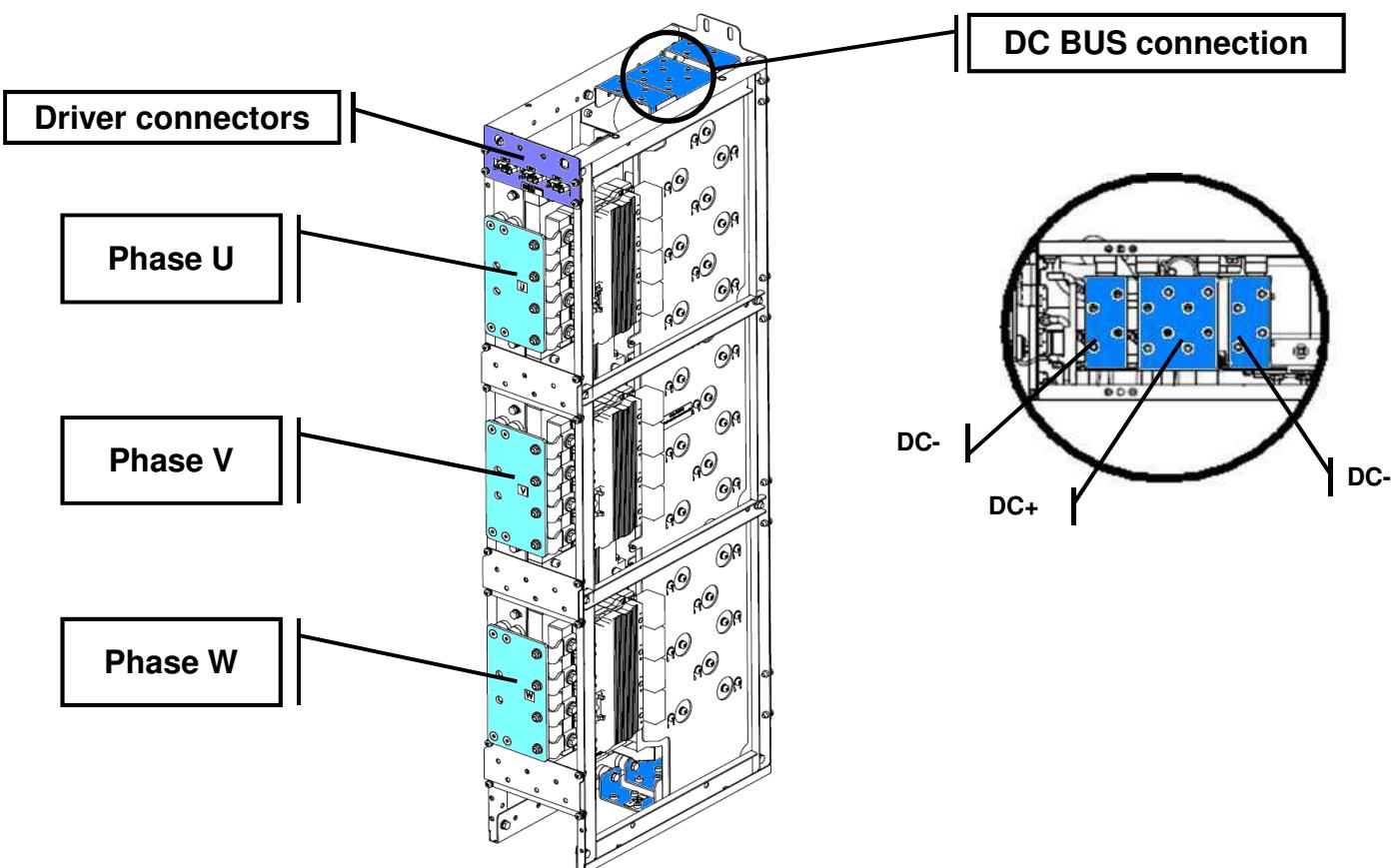
Thermal data				
$\Delta V/\Delta t_{WATER}$	Water flow of the 3-phase inverter	8	16	35
$\Delta P_{WATER}$	Water drop pressure of the inverter, with male and female connectors, 50% glycol, 16 L/min		580	mbar
Water pressure	Rated water pressure per inverter		3	bar
Coolant type	Recommended coolant	50% glycol / 50% water		-
TINLET	Cooling water inlet temperature	-20	45	60
Required cooling airflow	Airflow direction bottom to top on snubbers <sup>3)</sup>		1	m.s <sup>-1</sup>
VSUPPLY	Fan DC voltage supply	16	24	30
PFAN	Fan power consumption at typical voltage supply		90	W
LTE	Capacitor DC fan lifetime expectancy (L10 method)		57	kh

Gate Driver Characteristics		T <sub>AMBIENT</sub> =25°C unless otherwise specified		
Symbol	Conditions	min	typ	max
<b>Gate Driver / controller data</b>				
V <sub>S</sub>	supply voltage non stabilized	13	24	30
I <sub>S</sub>	V <sub>S</sub> = 24 V, F <sub>SW</sub> in kHz, I <sub>RMS</sub> in A	330 + 55×F <sub>SW</sub> + 0.00035×I <sub>RMS</sub> <sup>2</sup>		mA
V <sub>IT+</sub>	input threshold voltage HIGH	12.3		V
V <sub>IT-</sub>	input threshold voltage LOW		4.6	V
R <sub>IN</sub>	Input resistance	10		kΩ
C <sub>IN</sub>	Input capacitance	1		nF
<b>Measurement &amp; protection</b>				
I <sub>analog</sub>	Analogue current signal	250		A.V <sup>-1</sup>
I <sub>TRIP SC</sub>	Over current trip level (I <sub>analog</sub> OUT=10V)	2450	2 500	2550
CMN_TMP	Analogue temperature signal Th < 80°C	min	17 + 10.3×CMN_TMP	°C
		typ	19 + 10.5×CMN_TMP	°C
		max	20 + 10.5×CMN_TMP	°C
CMN_TMP	Analogue temperature signal Th > 80°C	min	26 + 8.8×CMN_TMP	°C
		typ	28 + 8.8×CMN_TMP	°C
		max	30 + 8.9×CMN_TMP	°C
T	Over temperature protection	110	115	120

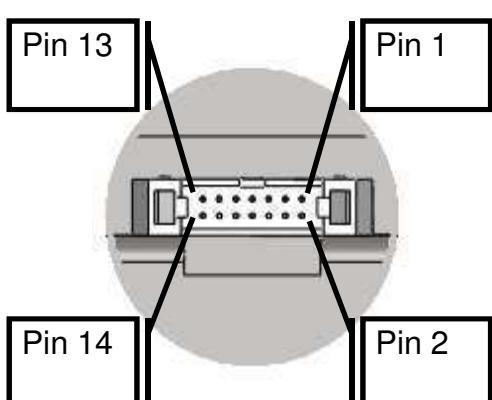
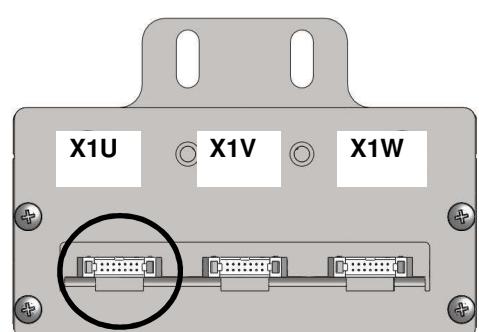


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## Electrical connection



## Drive connector assignment



HE10-14 male connector

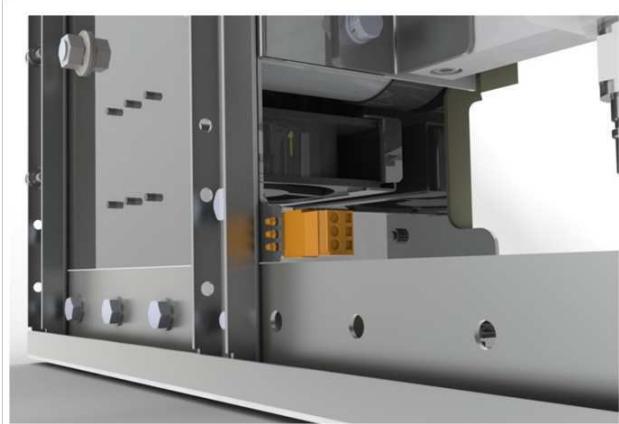
### X1U, X1V, X1W

Pin	Signal	Remark
1	Shield	
2	BOT IN (2)	positive 15V CMOS logic; 10 kΩ impedance, don't connect when using fiber optic
3	ERROR OUT (1)	LOW = NO ERROR; open Collector Output; max. 30 V / 15 mA don't connect when using fiber optic, propagation delay 1 µs min. pulselwidth error-memory-reset 9 µs
4	TOP IN (2)	positive 15V CMOS logic; 10 kΩ impedance don't connect when using fiber optic
5	Overtemp. OUT (1)	LOW = NO ERROR = 9DCB < 115 + 5°C open collector Output; max. 30 V / 15 mA „low“ output voltage < 0,6 V „high“ output voltage max. 30 V
6	+ 24 VDC IN	24 VDC (SKiiP 2: 20 - 30 V, SKiiP 3: 13 - 30 V)
7	+ 24 VDC IN	don't supply with 24V, when using +15 VDCIN supply voltage monitoring threshold 19,5 V
8	+15 VDC OUT	max. 50 mA auxiliary power supply when SKiiP system is supplied via pin 6/7
9	+15 VDC OUT	
10	GND	GND for power supply and
11	GND	GND for digital signals
12	Temp. analog OUT	max output current 5mA
13	GND aux	reference for analog output signals
14	I analog OUT	SKiiP 3 with Al2O3 ceramic substrate current actual value 8,0 V ⇔ 100 % IC @ 25 °C overcurrent trip level 10 V ⇔ 125 % IC @ 25 °C current value > 0 ⇔ SKiiP system is source current value < 0 ⇔ SKiiP system is sink SKiiP 3 with AlN ceramic substrate: refer to corresponding datasheet

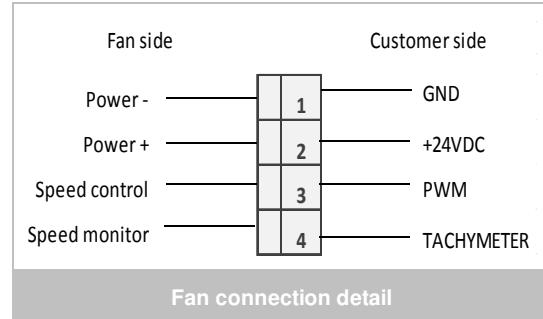
1) Open collector output, external pull up resistor necessary  
2) „high“ (max) 12,3 V, „low“ (min) 4,6 V; SKiiP 3: 1 nF capacitance added signal to GND

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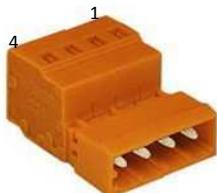
## DC fan connection



Fan connection detail

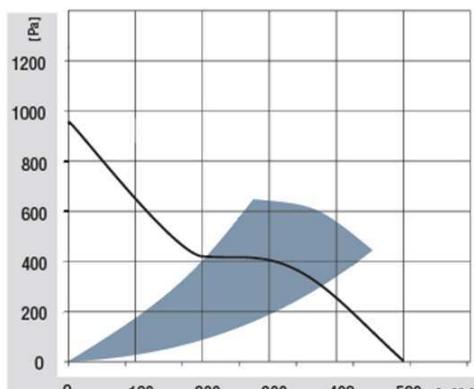


Fan connection detail

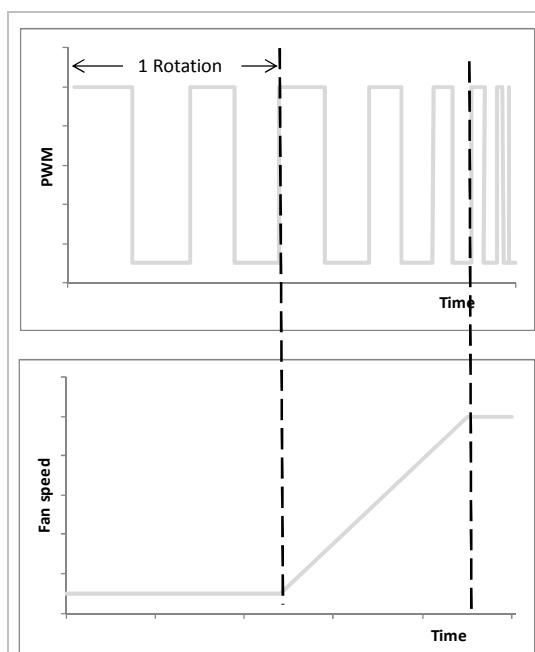


Pin	Designation
1	GND
2	+24VDC
3	PWM
4	MONITOR

## DC fan speed control

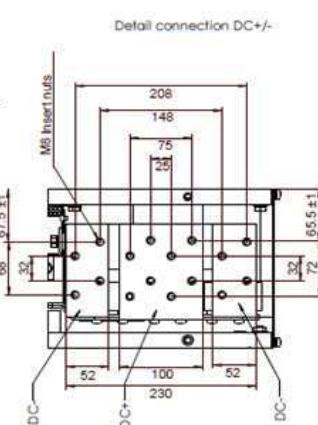
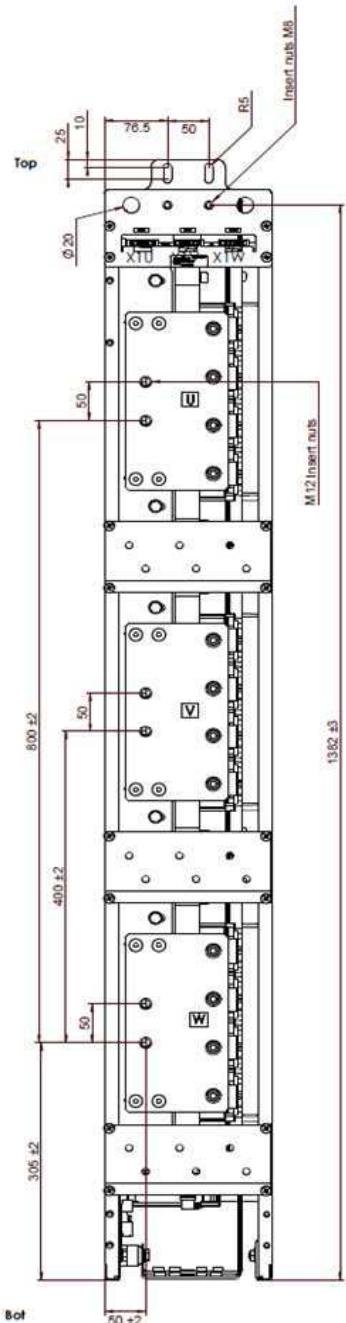
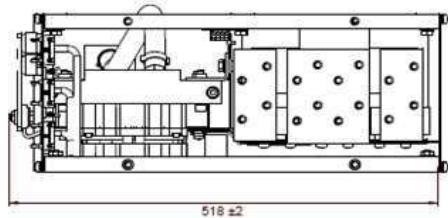
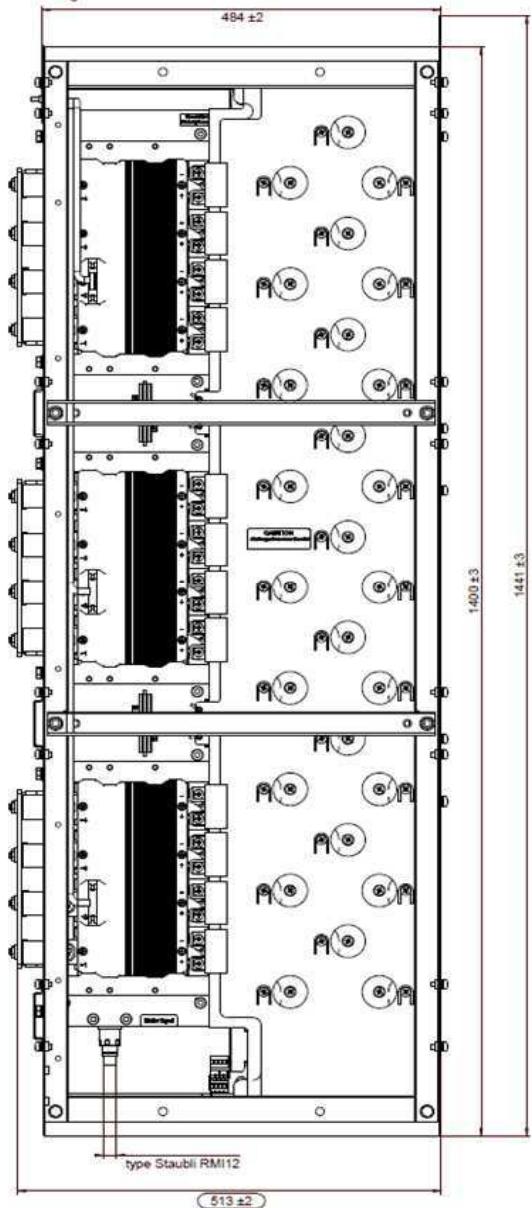
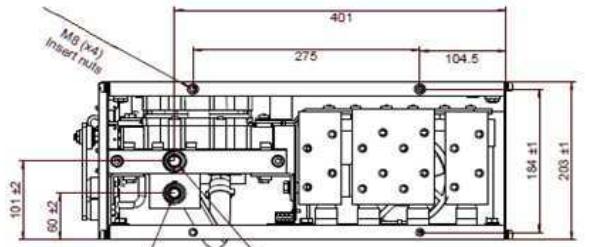


Characteristic pressure drop vs air flow



Speed control behavior

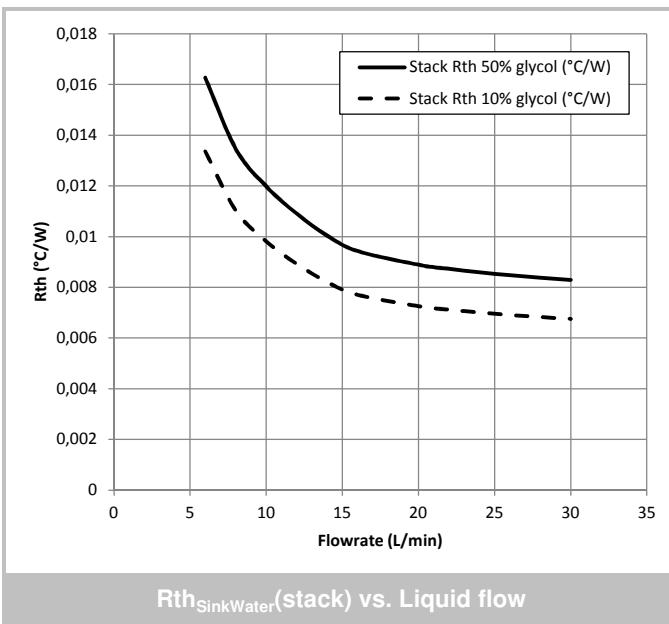
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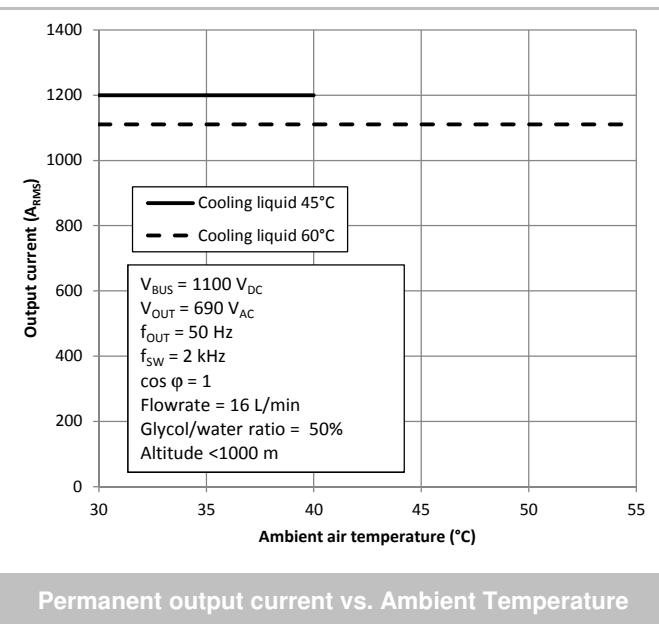
## Dimensions

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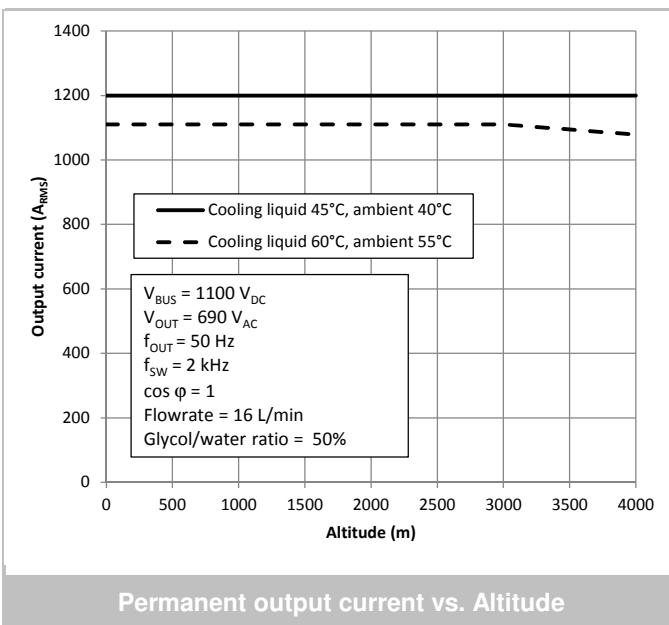
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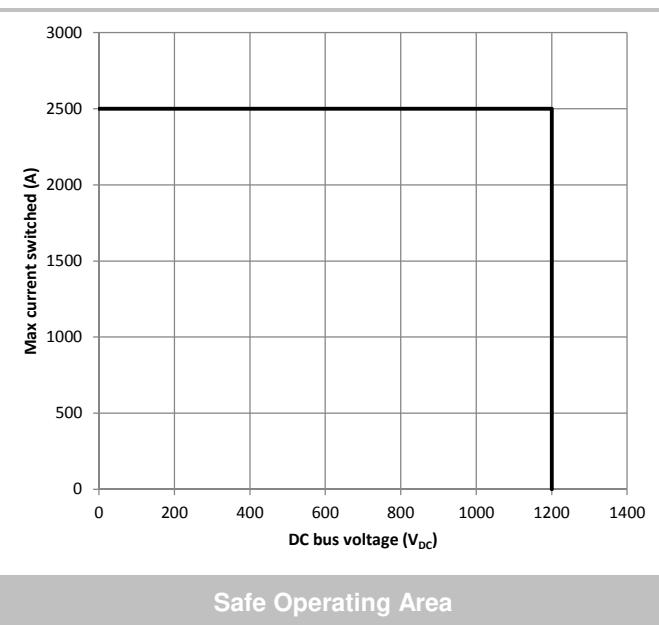
Rth<sub>SinkWater(stack)</sub> vs. Liquid flow



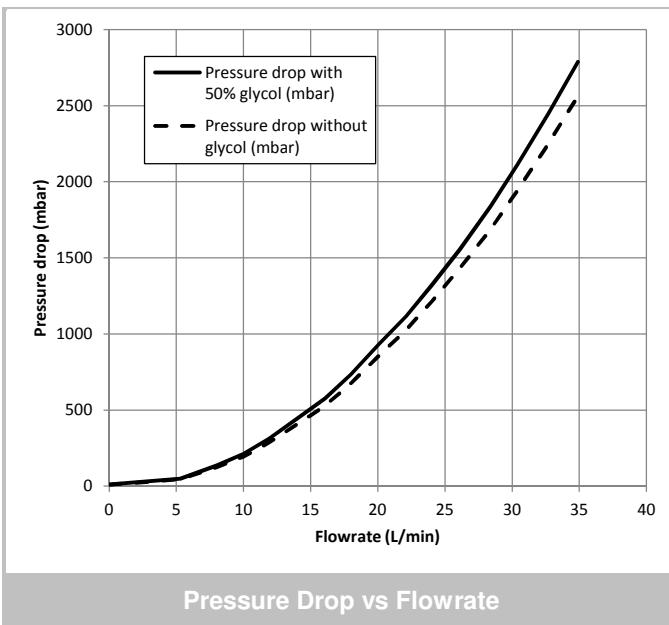
Permanent output current vs. Ambient Temperature



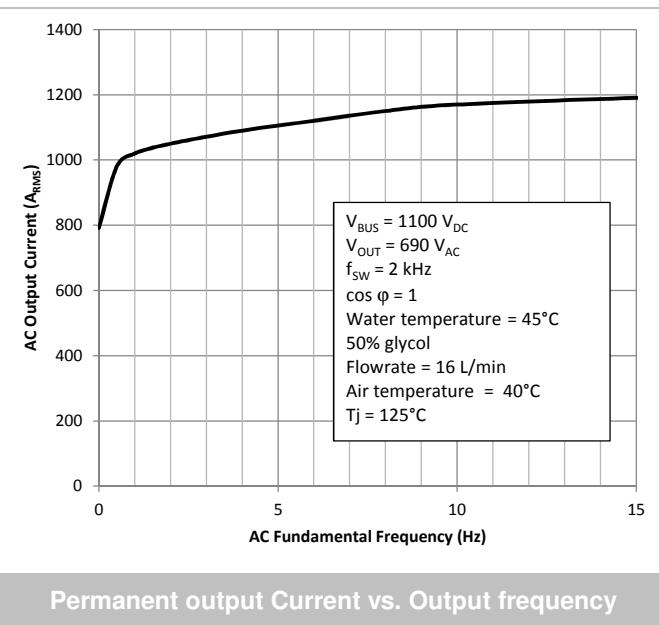
Permanent output current vs. Altitude



Safe Operating Area



Pressure Drop vs. Flowrate



Permanent output Current vs. Output frequency